

TOSHIBA TRANSISTOR SILICON NPN EPITAXIALTYPE (PCT PROCESS)

2SC3295

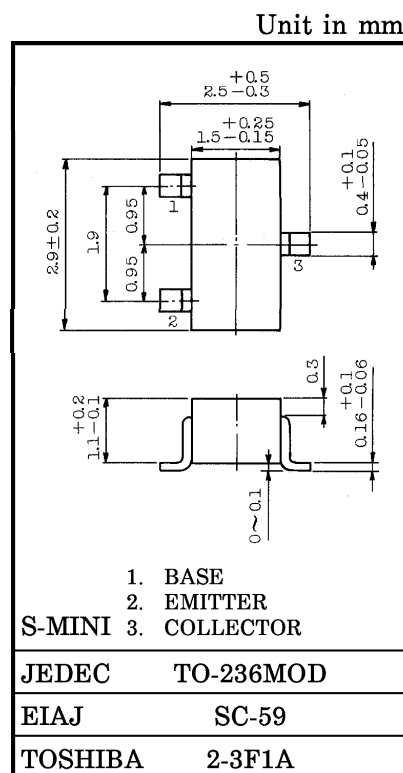
AUDIO FREQUENCY AMPLIFIER APPLICATIONS.

SWITCHING APPLICATIONS.

- High h_{FE} : $h_{FE}=600 \sim 3600$
- High Voltage : $V_{CEO}=50V$
- High Collector Current : $I_C=150mA$ (Max.)
- Small Package

MAXIMUM RATINGS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	150	mA
Base Current	I_B	30	mA
Collector Power Dissipation	P_C	150	mW
Junction Temperature	T_j	125	$^\circ C$
Storage Temperature Range	T_{stg}	$-55 \sim 125$	$^\circ C$

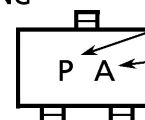
ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$)

Weight : 0.012g

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=50V, I_E=0$	—	—	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5V, I_C=0$	—	—	0.1	μA
DC Current Gain	h_{FE} (Note)	$V_{CE}=6V, I_C=2mA$	600	—	3600	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA, I_B=10mA$	—	0.12	0.25	V
Transition Frequency	f_T	$V_{CE}=10V, I_C=10mA$	100	250	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$	—	3.5	—	pF
Noise Figure	NF (1)	$V_{CE}=6V, I_C=0.1mA$ $f=100Hz, R_g=10k\Omega$	—	0.5	—	dB
	NF (2)	$V_{CE}=6V, I_C=0.1mA$ $f=1kHz, R_g=10k\Omega$	—	0.3	—	dB

Note: h_{FE} Classification A : 600~1800, B : 1200~3600

MARKING

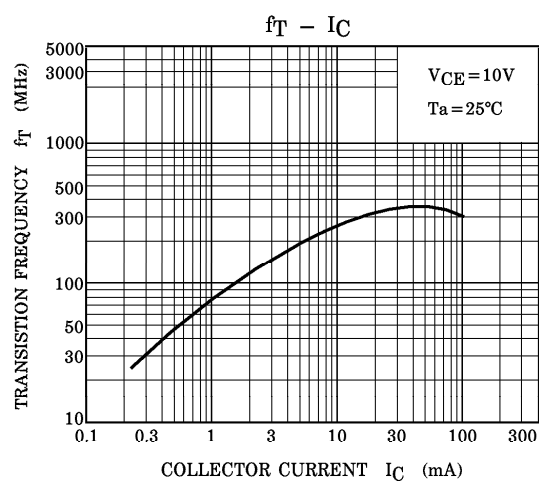
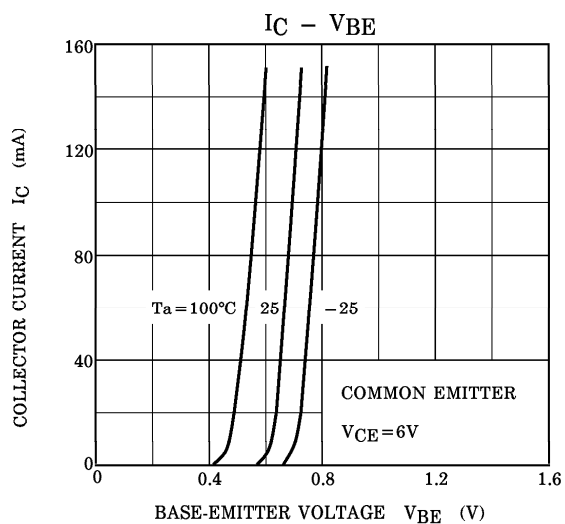
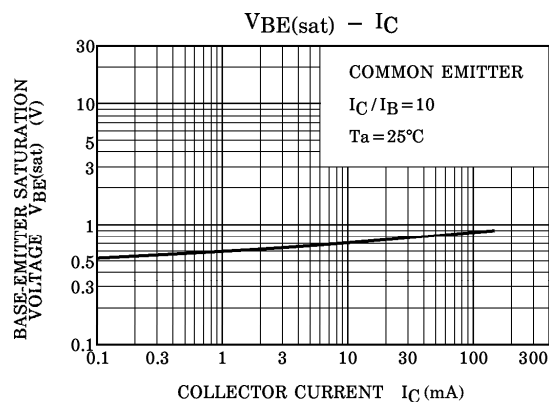
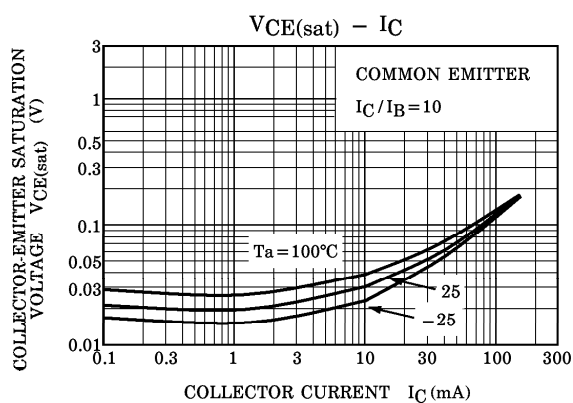
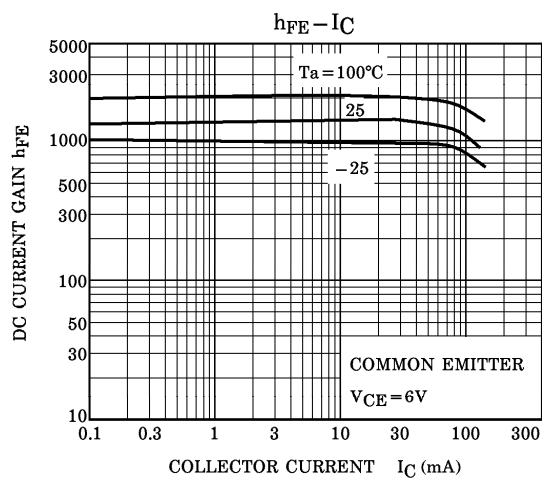
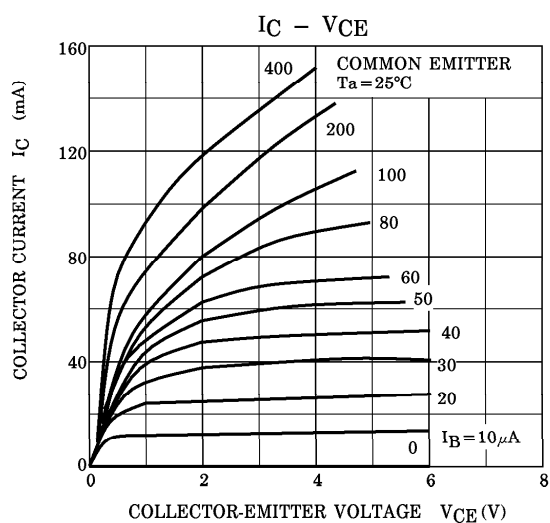


Type Name

 h_{FE} Rank

961001EAA2

● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.



961001EAA2'

- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

